



Image may be representation.
See specs for product details.

IXFN80N50P

Manufacturer Part Number:	IXFN80N50P
Manufacturer/Brand:	IXYS Corporation
Part of Description:	MOSFET N-CH 500V 66A SOT-227
Datasheets:	IXFN80N50P.pdf
RoHS Status:	Lead free / RoHS Compliant
Stock Condition:	New original, 2000 pcs Stock Available.
Ship From:	Hong Kong
Shipment Way:	DHL/Fedex/TNT/UPS/EMS

Specifications

Part Number	IXFN80N50P
Manufacturer	IXYS Corporation
Description	MOSFET N-CH 500V 66A SOT-227
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2000 pcs Stock
Series	PolarHV™
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	SOT-227-4, miniBLOC
Supplier Device Package	SOT-227B
Power Dissipation (Max)	700W (Tc)
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	500V
Current - Continuous Drain (Id) @ 25°C	66A
Rds On (Max) @ Id, Vgs	65 mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id	5V @ 8mA
Gate Charge (Qg) (Max) @ Vgs	195nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	12700pF @ 25V
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Packaging	Tube

IXFN80N50P is New Original in Stock, Search IXFN80N50P Datasheets, PDF, Inventory at Y-IC.com Online, Order IXFN80N50P IXYS Corporation with warrantied and confidence. RFQ IXFN80N50P : Info@Y-IC.com

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